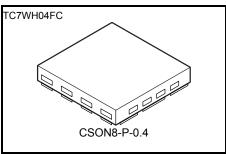
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7WH04FC

Triple Inverter

Features

- High-speed
- Low power dissipation
- High noise immunity
- Operation voltage range
- 5.5-V Tolerant inputs.
- : t_{pd} = 3.8ns (Typ.) at V_{CC} = 5 V
- :I_{CC}=2µA(Max.) at Ta=25°C
- :V_{NIH}=V_{NIL}=28%V_{CC}(Min.)
- :V_{CC}(opr.)=2~5.5V



Weight: 0.002g (typ.)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Ratingh	Unit
Power supply viltage	V _{CC}	-0.5~7.0	V
DC input voltage	VIN	-0.5~7.0	V
DC output voltage	Vout	$-0.5 \sim V_{CC} + 0.5$ (Note1)	V
Input diode current	Iк	-20	mA
Output diode current	IOK	±20 (Note2)	mA
DC output current	I _{OUT}	±25	mA
DC V _{CC} /GND current	ICC	±50	mA
Power dissipation	PD	150 (Note3)	mW
Storage temperature	T _{stg}	-65~150	°C

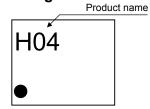
Note1 : High or Low State.

IOUT abusolute maximum rating must be observed.

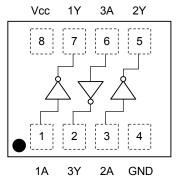
- Note2 : $V_{OUT} < GND$, $V_{OUT} > V_{CC}$
- Note3 : Mounted on an FR4 board.

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ t}, \text{ Cu Pad: } 11.56 \text{ mm}^2)$

Marking



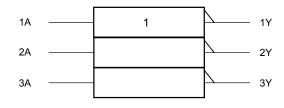
Pin Assignment (top view)



Truth Table

Α	Y
L	Н
Н	L

IEC Logic Diagram



Recommended Operationg Conditions

Characteristics	Symbol	Rathing	Unit
Power supply voltage	V _{CC}	2.0~5.5	V
Input voltage	V _{IN}	0~5.5	V
Output voltage	V _{OUT}	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
Input rise and fall time	dt/dv	0~100 (V_{CC} = 3.3 V \pm 0.3 V)	ns/V
	abav	0~20 (V _{CC} = 5 V \pm 0.5 V)	115/ V

DC Electrical Characteristics

Characteristic Sym		Test condition			Ta = 25°C			Ta = -40~85°C		unit
				V _{CC} (V)	Min.	Тур.	Max.	Min.	Max.	unit
				2.0	1.5	_	_	1.5	—	
High-level input voltage	VIH		_	3.0~5.5	V _{CC} × 0.7			V _{CC} × 0.7		V
				2.0			0.5		0.5	V
Low-level input voltage V _{IL}		_	3.0~5.5			V _{CC} × 0.3		V _{CC} × 0.3		
High-level output voltage		V _{IN =} V _{IL}	I _{OH} = –50 μA	2.0	1.9	2.0		1.9		- V
				3.0	2.9	3.0	_	2.9	_	
	V _{OH}			4.5	4.4	4.5	_	4.4	_	
			I _{OH} = –4 mA	3.0	2.58	_	_	2.48	_	
			I _{OH} = –8 mA	4.5	3.94			3.80		
Low-level output voltage		VIN = VIH	I _{OL} = 50 μΑ	2.0	_	0.0	0.1		0.1	
				3.0		0.0	0.1		0.1	
	VoL			4.5		0.0	0.1		0.1	
			I _{OL} = 4 mA	3.0			0.36		0.44	
			I _{OL} = 8 mA	4.5	_	_	0.36		0.44	
Input leakage current	I _{IN}	V _{IN =} 5.5 V	V _{IN =} 5.5 V or GND				±0.1		±1.0	μΑ
Quiescent supply current	ICC	VIN = VCC	VIN = V _{CC} or GND		_	_	2.0		20.0	μA

AC Electrical Characteristics (Input : $t_r = t_f = 3 \text{ ns}$)

Characteristic	Symbol		Test condition		Ta = 25°C			Ta = -40~85°C		Unit
			V _{CC} (V)	C _{L (} pF)	Min.	Тур.	Max.	Min.	Max.	Unit
Propagation delay time	^t pLH t _{pHL}	3.3 ± 0.3	15	_	5.0	7.1	1.0	8.5		
			0.0 ± 0.0	50	_	7.5	10.6	1.0	12.0	ns
			5.0 ± 0.5	15	_	3.8	5.5	1.0	6.5	
		5.0 ± 0.5	5.0 ± 0.5	50		5.3	7.5	1.0	8.5	
Input capacitance	C _{IN}				_	4	10	_	10	pF
Power dissipation capacitanse	C _{PD}		(Note 4)		_	18	_	_	_	pF

Note 4 : C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

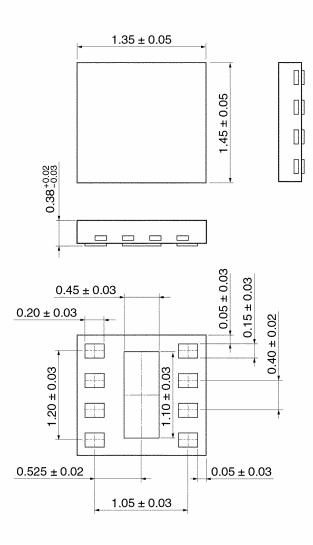
Average operating current can be obtained by the equation:

 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/3$

TOSHIBA

Package Dimensions

CSON8-P-0.4



Weight: 0.002 g (Typ.)

Unit: mm

4

RESTRICTIONS ON PRODUCT USE

030619EBA

- The information contained herein is subject to change without notice.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of TOSHIBA or others.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor
 devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical
 stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of
 safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of
 such TOSHIBA products could cause loss of human life, bodily injury or damage to property.

In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..

- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- TOSHIBA products should not be embedded to the downstream products which are prohibited to be produced and sold, under any law and regulations.